

TURBO 2 ULTRAFAST HIGH VOLTAGE RECTIFIER

Table 1: Main Product Characteristics

| | |
|----------------|--------------|
| $I_{F(AV)}$ | 30 A |
| V_{RRM} | 600 V |
| T_j | 175°C |
| V_F (typ) | 1.0 V |
| t_{rr} (max) | 65 ns |

FEATURES AND BENEFITS

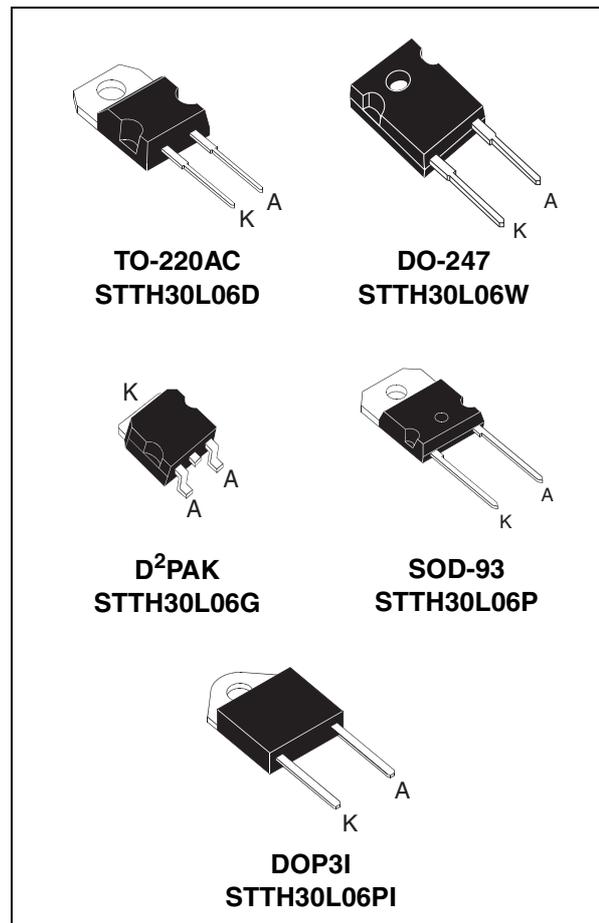
- Ultrafast switching
- Low reverse current
- Low thermal resistance
- Reduces switching & conduction losses

DESCRIPTION

The STTH30L06, which is using ST Turbo 2 600V technology, is specially suited for use in switching power supplies, and industrial applications, as rectification and discontinuous mode PFC boost diode.

Table 2: Order Codes

| Part Number | Marking |
|---------------|-------------|
| STTH30L06D | STTH30L06D |
| STTH30L06G | STTH30L06G |
| STTH30L06G-TR | STTH30L06G |
| STTH30L06W | STTH30L06W |
| STTH30L06P | STTH30L06P |
| STTH30L06PI | STTH30L06PI |



STTH30L06

Table 3: Absolute Ratings (limiting values)

| Symbol | Parameter | | Value | Unit | |
|--------------|--|---|--|------|--------------------|
| V_{RRM} | Repetitive peak reverse voltage | | 600 | V | |
| $I_{F(RMS)}$ | RMS forward current | | 50 | A | |
| $I_{F(AV)}$ | Average forward current | TO-220AC / TO-247 / D ² PAK / SOT-93 | $T_c = 125^{\circ}\text{C}$ $\delta = 0.5$ | 30 | A |
| | | DOP3I | $T_c = 95^{\circ}\text{C}$ $\delta = 0.5$ | | |
| I_{FSM} | Surge non repetitive forward current | | $t_p = 10\text{ms}$ sinusoidal | 160 | A |
| T_{stg} | Storage temperature range | | -65 to + 175 | | $^{\circ}\text{C}$ |
| T_j | Maximum operating junction temperature | | 175 | | $^{\circ}\text{C}$ |

Table 4: Thermal Resistance

| Symbol | Parameter | | Value (max.) | Unit |
|---------------|------------------|---|--------------|-----------------------------|
| $R_{th(j-c)}$ | Junction to case | TO-220AC / TO-247 / D ² PAK / SOT-93 | 1.1 | $^{\circ}\text{C}/\text{W}$ |
| | | DOP3I | 1.7 | |

Table 5: Static Electrical Characteristics

| Symbol | Parameter | Test conditions | | Min. | Typ | Max. | Unit |
|------------|-------------------------|-----------------------------|--------------------|------|------|------|---------------|
| I_R^* | Reverse leakage current | $T_j = 25^{\circ}\text{C}$ | $V_R = V_{RRM}$ | | | 25 | μA |
| | | $T_j = 150^{\circ}\text{C}$ | | 80 | 800 | | |
| V_F^{**} | Forward voltage drop | $T_j = 25^{\circ}\text{C}$ | $I_F = 30\text{A}$ | | | 1.55 | V |
| | | $T_j = 150^{\circ}\text{C}$ | | 1.0 | 1.25 | | |

Pulse test: * $t_p = 5\text{ ms}$, $\delta < 2\%$

** $t_p = 380\ \mu\text{s}$, $\delta < 2\%$

To evaluate the conduction losses use the following equation: $P = 0.95 \times I_{F(AV)} + 0.010 I_{F(RMS)}^2$

Table 6: Dynamic Characteristics

| Symbol | Parameter | Test conditions | | Min. | Typ | Max. | Unit |
|----------|--------------------------|-----------------------------|---|------|------|------|------|
| t_{rr} | Reverse recovery time | $T_j = 25^{\circ}\text{C}$ | $I_F = 0.5\text{A}$ $I_{rr} = 0.25\text{A}$ $I_R = 1\text{A}$ | | | 65 | ns |
| | | | $I_F = 1\text{A}$ $di_F/dt = 50\text{ A}/\mu\text{s}$ $V_R = 30\text{V}$ | | 65 | 90 | |
| I_{RM} | Reverse recovery current | $T_j = 125^{\circ}\text{C}$ | $I_F = 30\text{A}$ $V_R = 400\text{V}$ $di_F/dt = 100\text{ A}/\mu\text{s}$ | | 11.5 | 16 | A |
| t_{fr} | Forward recovery time | $T_j = 25^{\circ}\text{C}$ | $I_F = 30\text{A}$ $di_F/dt = 100\text{ A}/\mu\text{s}$ $V_{FR} = 1.1 \times V_{Fmax}$ | | | 500 | ns |
| V_{FP} | Forward recovery voltage | $T_j = 25^{\circ}\text{C}$ | $I_F = 30\text{A}$ $di_F/dt = 100\text{ A}/\mu\text{s}$ $V_{FR} = 1.1 \times V_{Fmax}$ | | 2.5 | | V |

Figure 1: Conduction losses versus average forward current

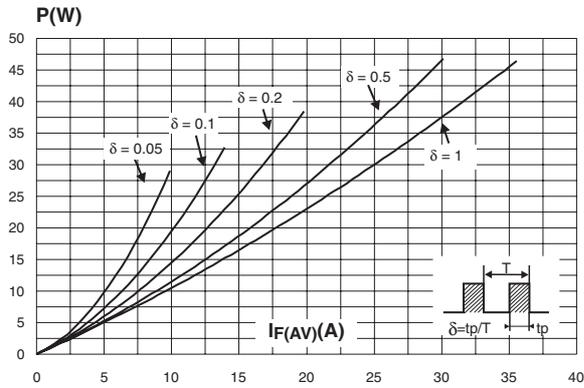


Figure 2: Forward voltage drop versus forward current

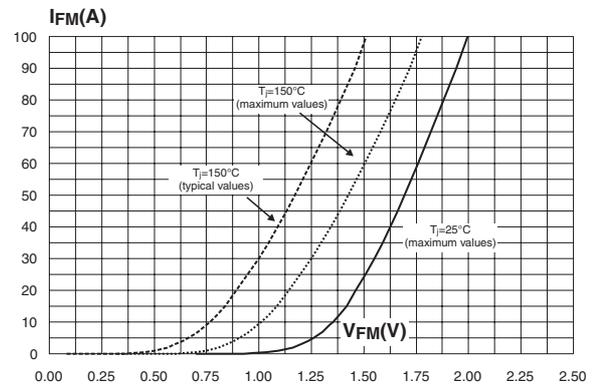


Figure 3: Relative variation of thermal impedance junction to case versus pulse duration

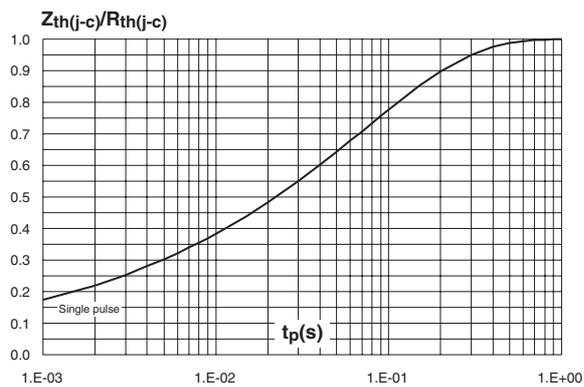


Figure 4: Peak reverse recovery current versus dIF/dt (typical values)

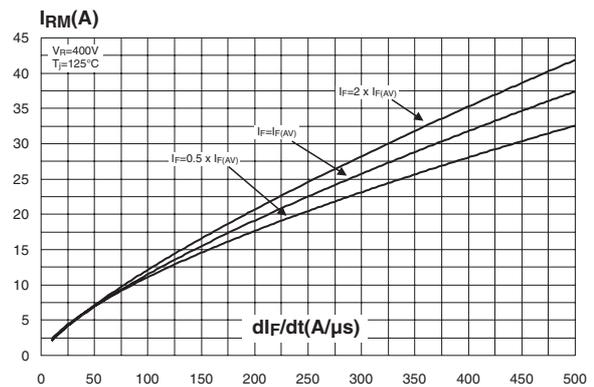


Figure 5: Reverse recovery time versus dIF/dt (typical values)

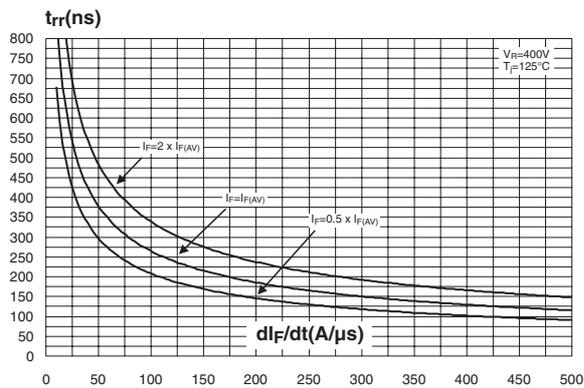


Figure 6: Reverse recovery charges versus dIF/dt (typical values)

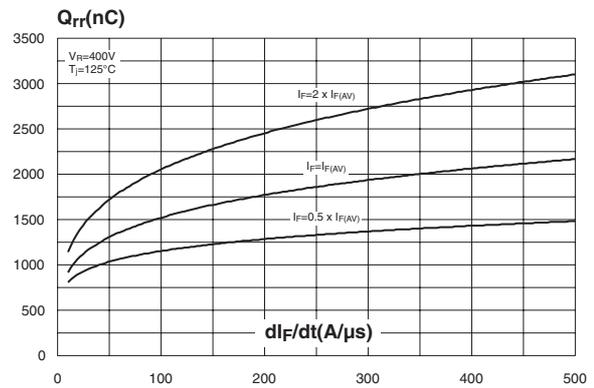


Figure 7: Reverse recovery softness factor versus di_F/dt (typical values)

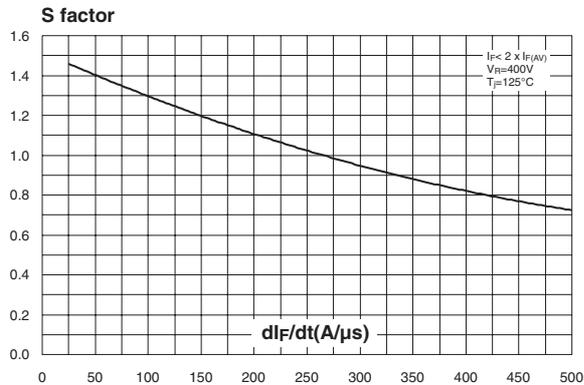


Figure 8: Relative variations of dynamic parameters versus junction temperature

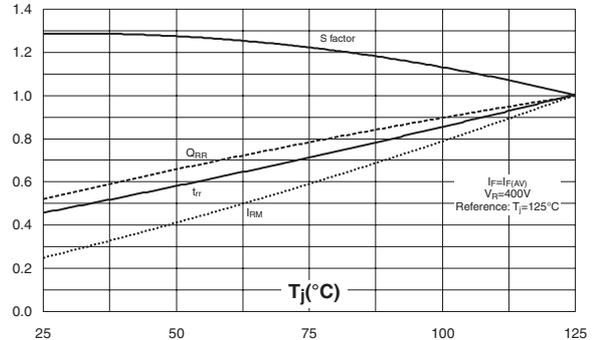


Figure 9: Transient peak forward voltage versus di_F/dt (typical values)

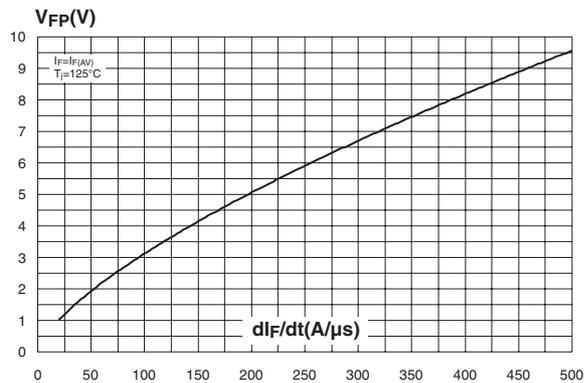


Figure 10: Forward recovery time versus di_F/dt (typical values)

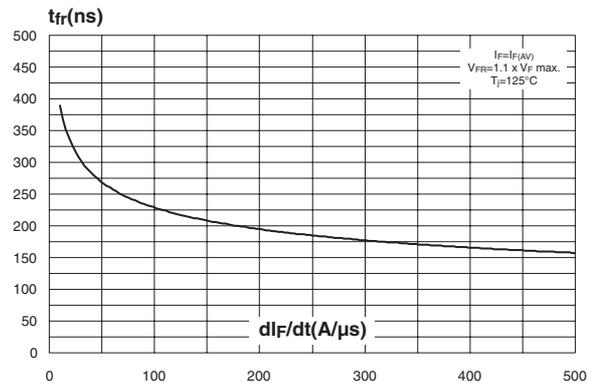


Figure 11: Junction capacitance versus reverse voltage applied (typical values)

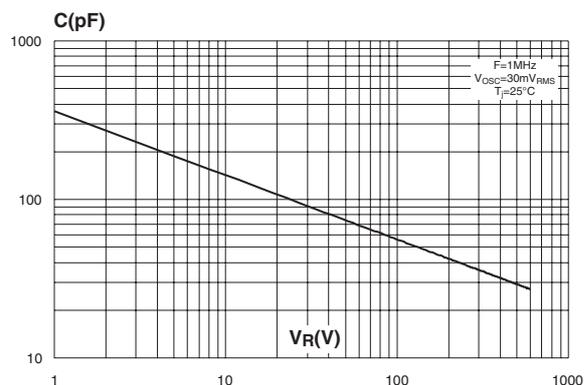


Figure 12: Thermal resistance junction to ambient versus copper surface under tab (epoxy FR4, $e_{CU}=35\mu m$) (D^2PAK)

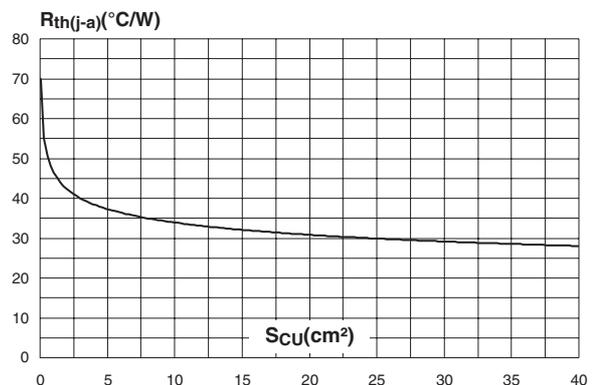


Figure 13: D²PAK Package Mechanical Data

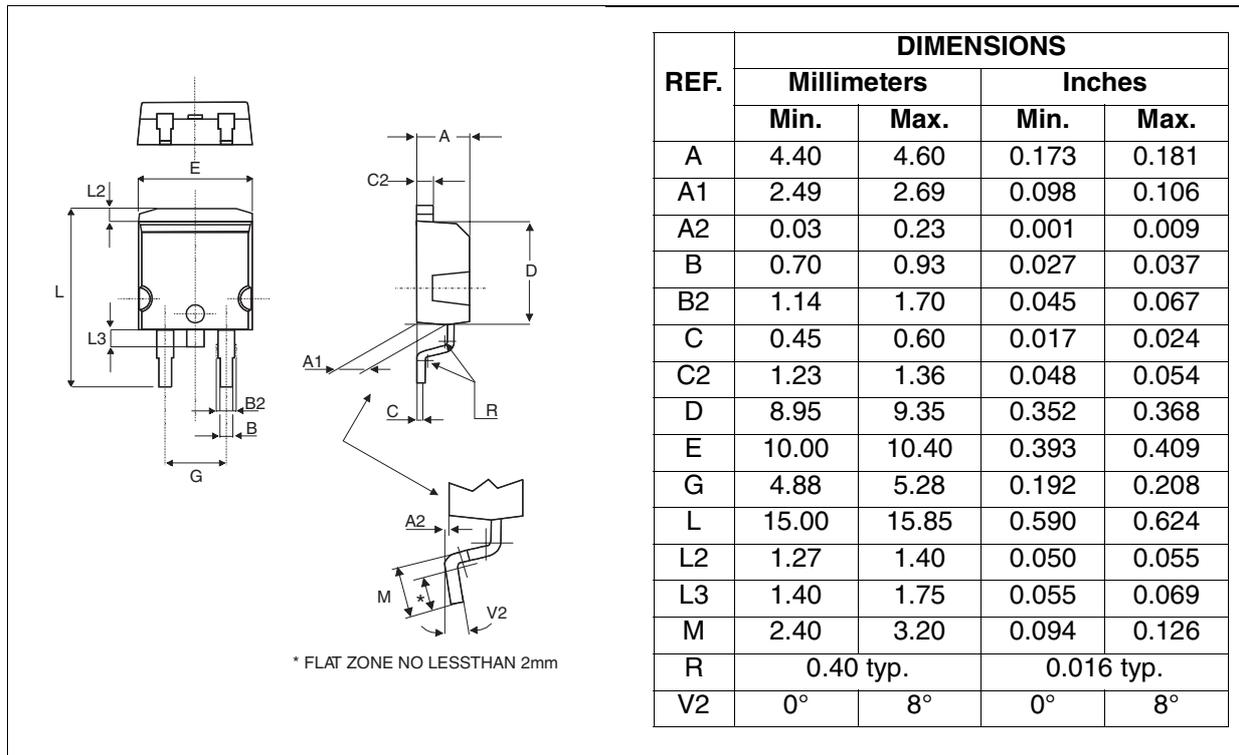


Figure 14: D²PAK Foot Print Dimensions (in millimeters)

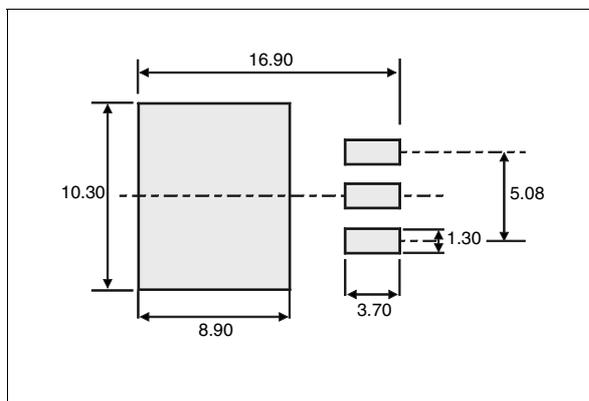


Figure 15: DO-247 Package Mechanical Data

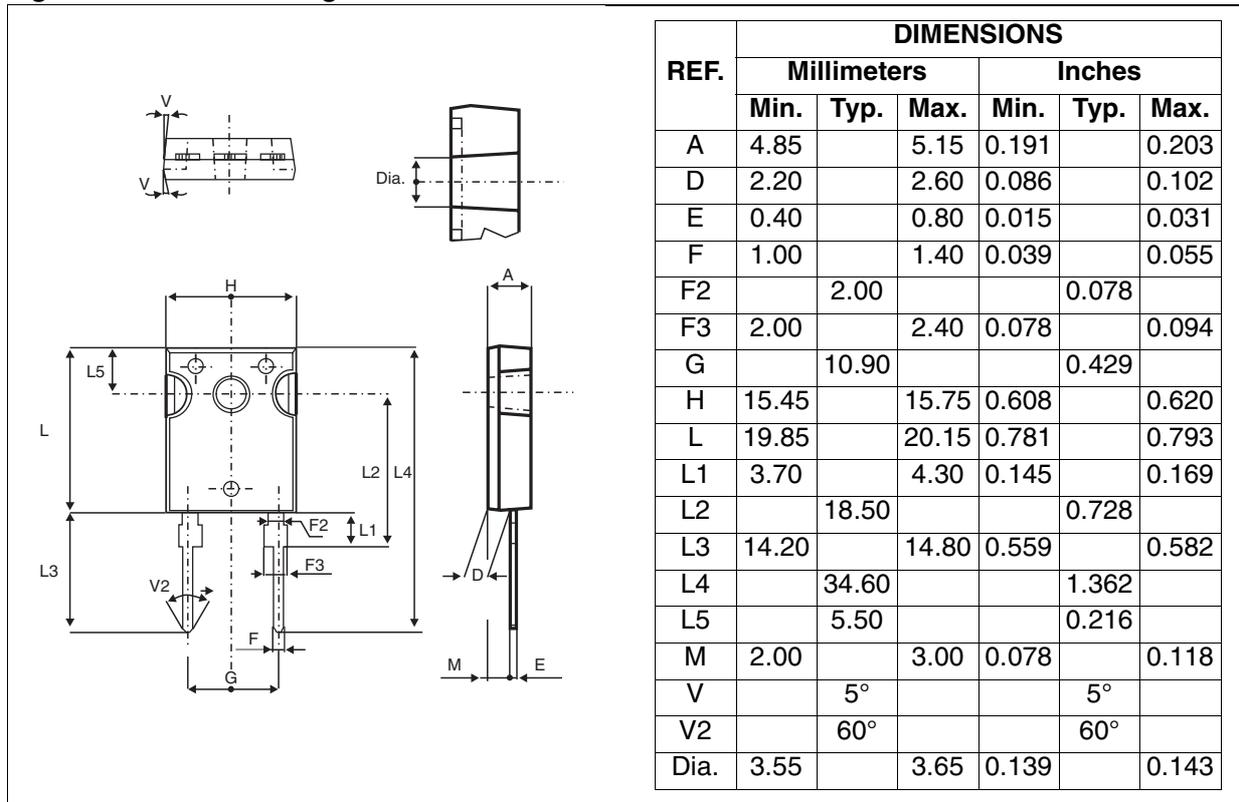


Figure 16: SOD-93 Package Mechanical Data

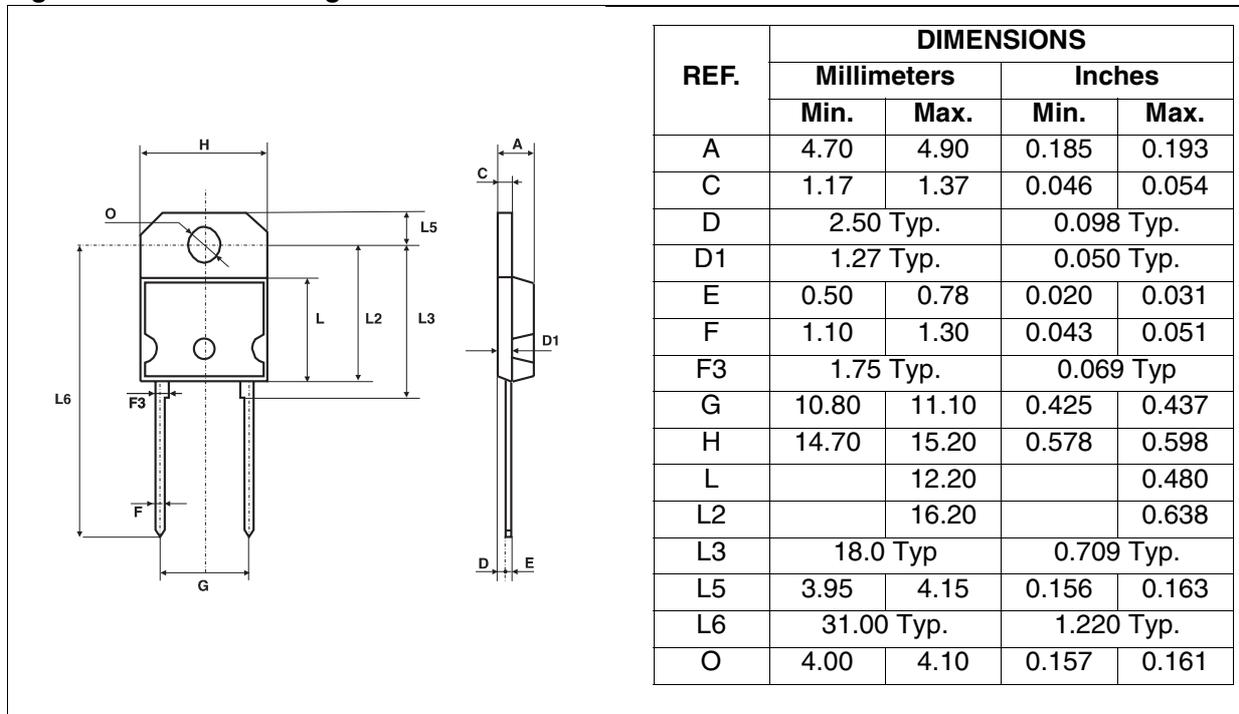


Figure 17: SOD-93 Package Mechanical Data

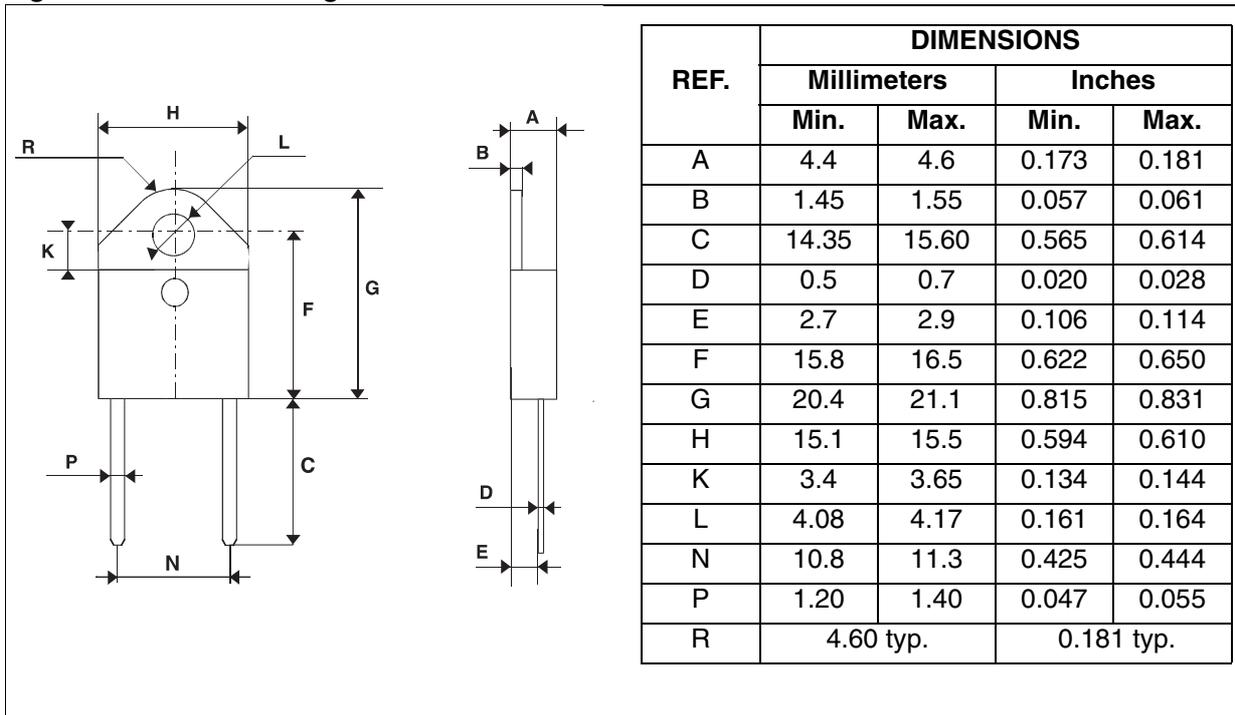


Figure 18: TO-220AC Package Mechanical Data

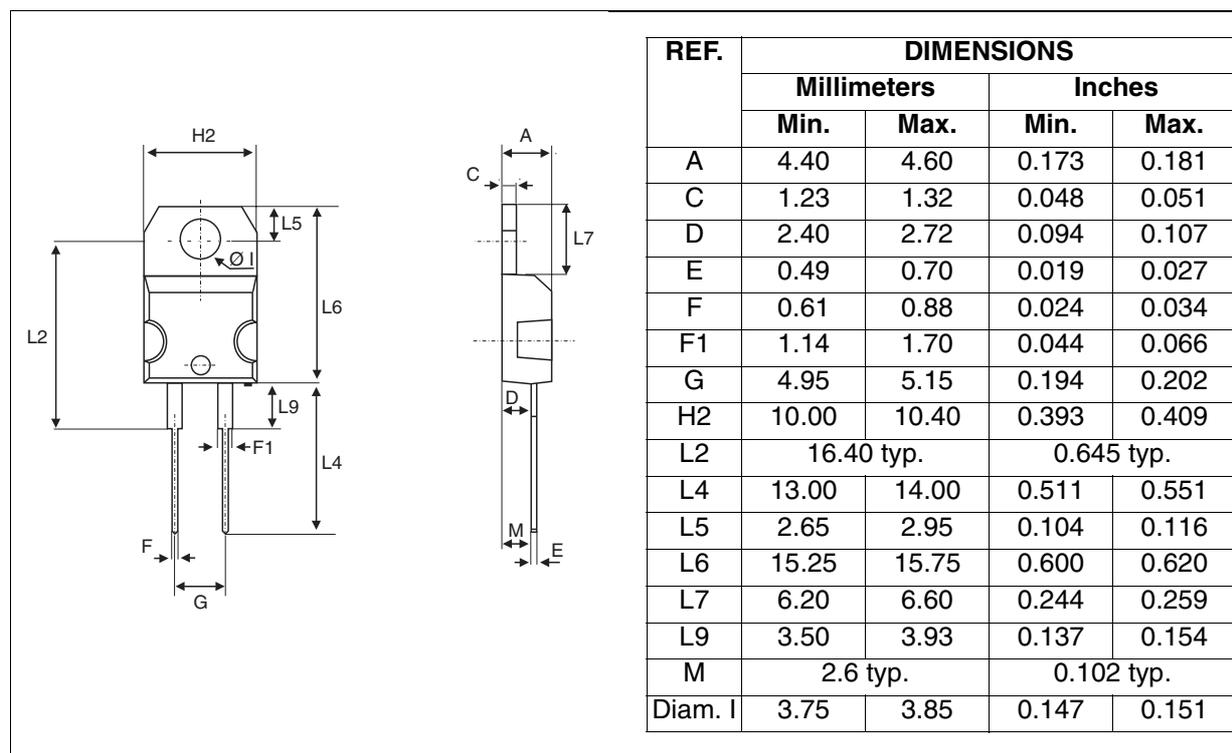


Table 7: Ordering Information

| Ordering type | Marking | Package | Weight | Base qty | Delivery mode |
|---------------|------------|--------------------|--------|----------|---------------|
| STTH30L06D | STTH30L06D | TO-220AC | 1.90 g | 50 | Tube |
| STTH30L06G | STTH30L06G | D ² PAK | 1.48 g | 50 | Tube |
| STTH30L06G-TR | STTH30L06G | D ² PAK | 1.48 g | 1000 | Tape & reel |
| STTH30L06W | STTH30L06W | DO-247 | 4.40 g | 30 | Tube |
| STTH30L06P | STTH30L06P | SOD-93 | 3.79 g | 30 | Tube |
| STTH30L06P | STTH30L06P | DOP3I | 4.46 g | 30 | Tube |

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.8 m.N. (TO-220FPAC) / 0.55 m.N. (TO-220AC)
- Maximum torque value: 1.0 m.N. (TO-220FPAC) / 0.70 m.N. (TO-220AC)

Table 8: Revision History

| Date | Revision | Description of Changes |
|-------------|----------|---|
| 07-Sep-2004 | 1 | First issue. |
| 21-Oct-2004 | 2 | DOP3I package added. |
| 11-Jan-06 | 3 | Table 3 on page 2: <ul style="list-style-type: none"> · I_{F(RMS)} corrected from 30A to 50A · I_{F(AV)} corrected from 50A to 30A |

Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specifications mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. STMicroelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics.

The ST logo is a registered trademark of STMicroelectronics.
All other names are the property of their respective owners

© 2005 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan -
Malaysia - Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com

